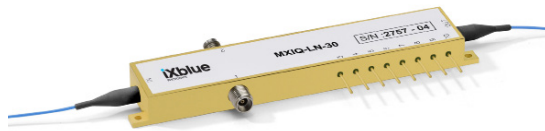


MXIQ-LN-30

1550 nm band wide bandwidth IQ Modulator

MODULATOR



MXIQ-LN-30 is a wide bandwidth, low insertion loss Dual Parallel Mach-Zehnder Modulator. Its proprietary “Magic Junction” (patent n° US2008193077) confers it an unmatched low insertion loss, and its X-cut design guarantees high stability and zero chirp in a wide range of operational conditions.

MXIQ-LN-30 modulator is a key device dedicated to complex modulation scheme such as QPSK, QAM and OFDM up to 56 Gbaud.

FEATURES

- Wide bandwidth
- X-cut for high stability
- Low insertion loss

APPLICATIONS

- QPSK, QAM, OFDM

RELATED EQUIPMENTS

- Analog driver DR-AN-HO
- MBC-IQ Automatic Bias Controller
- ModBox-IQ

MXIQ-LN-30 Performance Highlights

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1580	nm
Insertion loss	-	5	7	dB
Electro-optical bandwidth	25	30	-	GHz

Specifications given at 25 °C, 1550 nm

Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optic bandwidth	S_{21}	RF electrodes, from 2 GHz	25	30	-	GHz
Ripple S_{21}	ΔS_{21}	RF electrodes	-	0.5	1	dB
Electrical return loss	S_{11}	RF electrodes, 0 - 25 GHz	-	-12	-10	dB
$V\pi$ RF @ 50 kHz	$V\pi_{RF_{50\text{ kHz}}}$	RF ₁ & RF ₂ electrodes	-	5.5	7	V
$V\pi$ DC _{1,2} electrodes	$V\pi_{DC_{1,2}}$	DC ₁ & DC ₂ electrodes	-	7	7.5	V
$V\pi$ DC ₃ electrodes	$V\pi_{DC_3}$	DC ₃ electrodes	-	9	12	V
Impedance matching	Z_{in-RF}	-	-	50	-	Ω
DC input impedance	Z_{in-DC}	-	1	-	-	M Ω

Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	λ	-	1530	1550	1580	nm
Insertion loss	IL	Without connectors	-	5	7	dB
Optical return loss	ORL	-	-40	-45	-40	dB
Chirp	α	-	-0.1	0	-0.1	-

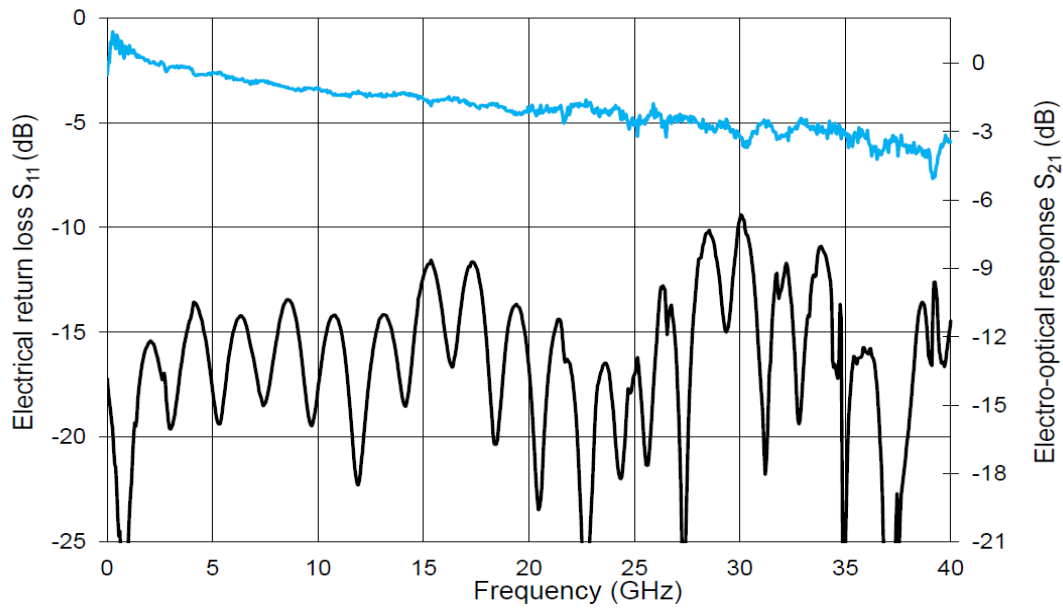
All specifications given at 25°C, 1550 nm, unless differently specified

Absolute Maximum Ratings

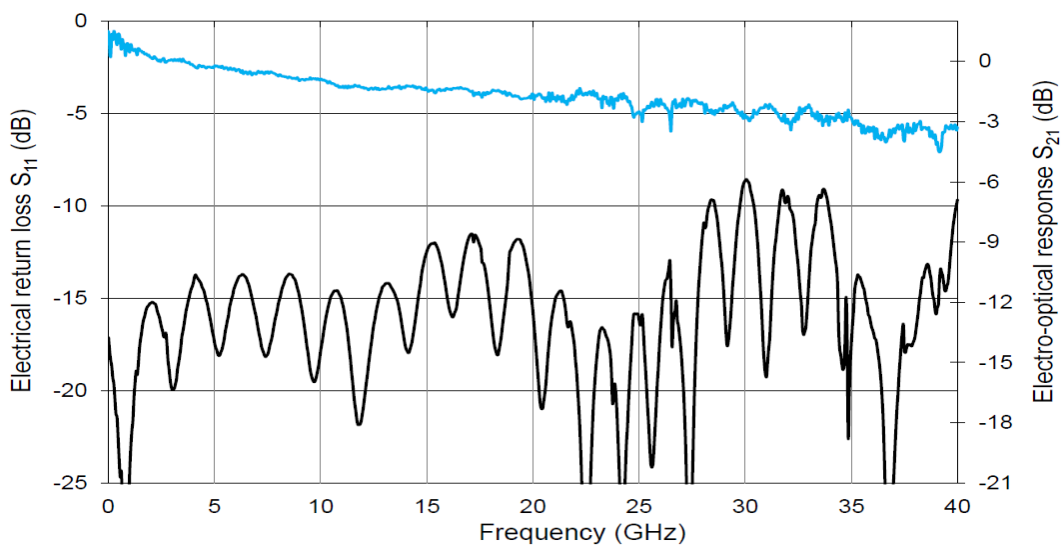
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	EP_{in}	-	28	dBm
Bias voltage	V_{bias}	-20	+20	V
Optical input power	OP_{in}	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

Typical Curve S_{21} & S_{11} from RF₁ Electrode



Typical Curve S_{21} & S_{11} from RF₂ Electrode



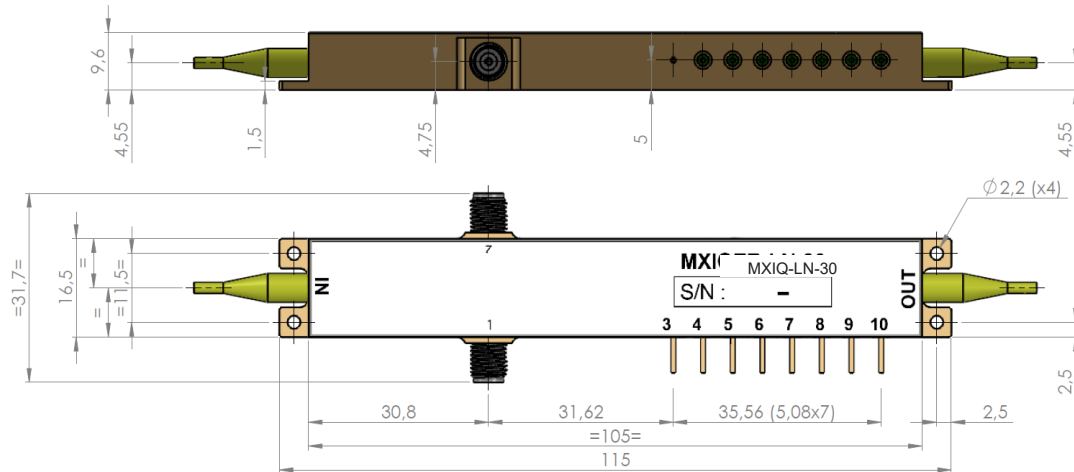
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Mechanical Diagram and Pinout

All measurements in mm



Port	Function	Note
IN / OUT	Optical input port / Optical output port	Polarization maintaining 1550 nm Corning PM 15-U25D length: 1.5 meter, buffer diameter: 900 μ m
1 / 2	RF ₁ input port / RF ₂ input port	Female K (SMA compatible)
3	Ground	Pin feed through diameter 1.0 mm
4 / 5 / 6	DC ₂ / DC ₁ / DC ₃	Pin feed through diameter 1.0 mm
7 / 8	Photodiode 1 anode / cathode	Pin feed through diameter 1.0 mm
9 / 10	Photodiode 2 cathode / anode	Pin feed through diameter 1.0 mm

Ordering information

MXIQ-LN-30-PD-Y-Z-AB-CD

Y = Input fiber : P Polarisation maintaining

Z = Input fiber : P Polarisation maintaining S Standard single mode

AB = Output connector : 00 bare fiber FA FC/APC FC FC/SPC

CD = Output connector : 00 bare fiber FA FC/APC FC FC/SPC